FEB 0.9 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Raul-Adrian Cernea et al.

Title:

Non-Volatile Memory and Method With Bit Line Coupled

Compensation

Application No.:

10/667,222

Filing Date:

September 17, 2003

Examiner:

Unassigned

Group Art Unit:

2818

Docket No.:

SNDK.308US0

Conf. No.:

7021

Certificate of Mailing Under 37 CFR 1.8

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on ______February 5, 2004_____

Signature

Signature

5. Buggi

Mail Stop Missing Parts Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Dear Sir:

Pursuant to 37 C.F.R. §§ 1.56, 1.97 and 1.98, Applicants call the documents listed on the enclosed Form PTO-1449 to the Examiner's attention in this patent application.

This application has a filing date after June 30, 2003. Therefore copies of the U.S. Patents listed on the accompanying Form PTO-1449 are not enclosed.

Citation of these documents shall not be construed as (1) an admission that the documents are prior art with respect to the invention or inventions claimed in this application, (2) a representation that a search has been made (other than as indicated by any cited document), or (3) an admission that the cited information is, or is considered to be, material to patentability as defined in § 1.56(b).

Attorney Docket No.: SNDK.308US0

Application No.: 10/667,222

This information disclosure statement is submitted under 37 C.F.R. § 1.97(b) and consequently no fee should be required. The Commissioner is authorized, however, to charge any fee that may be required, or to credit any overpayment, against Deposit Account No. 502664 as set forth in the accompanying transmittal letter.

Respectfully submitted,

Gerald P. Parsons

Reg. No. 24,486

February 5, 2004

Date

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W.	a\t	9	U.S. P	atent Documents					
*Examiner B. Initial	DEMARK	Document Number	Date	Name	Class	Subclass	Filing D If Approp		
	1	5,172,338	12/15/92	Mehrotra et al.				-	
	2	5,570,315	10/29/96	Tanaka et al.					
	3	5,595,924	1/21/97	Yuan et al.					
	4	5,768,192	6/16/98	Eitan					
	5	5,774,397	6/30/98	Endoh et al.	·				
	6	5,903,495	5/11/99	Takeuchi et al.					
	7	6,011,725	1/4/00	Eitan					
	8	6,046,935	4/4/00	Takeuchi et al.					
			U.S. Published Pa	atent Application Docu	iments		-		
*Examiner Initial		Document Number	Date '	Name	Class	Subclass	Filing Date If Appropriate		
			Foreign	Patent Documents					
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		Document	Date	Country	Class	Subclass	Yes	No	
		OTHER A	RT (Including A	uthor, Title, Date, Pert	inent Pages, I	Etc.)			
	9	Eitan et al., "NROM: A Novel Localized Trapping, 2-Bit Nonvolatile Memory Cell," IEEE Electron Device Letters, Vol. 21, No. 11, November 2000, pp. 543-545.							
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